2D material integrated macroporous electrodes for Li-ion batteries†

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Three-dimensionally structured architectures are known to improve the performance of electrodes used in Li ion battery systems. In addition, integration of select 2D materials into 3D structures, for enhancing both electrical conductivity and electrochemical activity, will prove advantageous. Here a scalable one-step chemical vapor deposition technique is demonstrated for the controlled etching and simultaneous graphene growth on stainless steel substrates resulting in a 3D micro-mesh architecture that is ideal for high rate/high capacity electrodes; the graphene coated 3D stainless steel current collector is used with an MoS$_2$ electrode material for demonstrating high stability and rate capacity in Li-ion batteries.

Introduction

The discovery of a synthesis process for fabricating single layer graphene with extraordinary properties had led to a paradigm shift in the use of such two-dimensional (2D) materials for various applications. From doping of graphene with various elements such as boron,$^{1,2}$ nitrogen,$^3$ transition metals,$^4$ etc. to fabricating composites at the nanoscale,$^5$-7 fascinating structures with varying electrical, chemical and mechanical properties have been reported. Though several methods such as physical exfoliation, wet chemical exfoliation, arc discharge, etc. have been reported$^{8-11}$ to synthesize variants of single layer to multi-layer graphene, chemical vapor deposition (CVD) remains a viable option for direct one-step deposition of high quality films over large continuous areas.$^{12-15}$

The flexibility to tune electrical properties, high electro-chemical stability and precise control on the number of deposited layers enable the application of graphene in diverse areas, one of the recent interests being thin film lithium ion batteries (LIBs) as both anodes$^{16,17}$ and current collectors.$^{18-21}$ As an anode, although presenting increased volumetric power densities, the limited availability of active material constraints energy densities in thin film batteries, which is a major limitation for such a device configuration. Increase in surface area of the electrode by engineering electrodes in 3D can enhance the energy density of the device without compromise on the power density. CVD growth of 2D graphene onto pre-fabricated highly porous 3D substrates results either in uneven penetration of the carbon precursor into the 3D network and/or collapse of the 3D structure at high deposition temperatures.

In the context of thin film and miniaturized energy storage, as the size of the device shrinks, the equivalent resistances increases exponentially, limiting the performance. In order to overcome this, proficient packing of electrode material is required, which is a challenge in a planar configuration. Charge transfer to the bulk of the electrode in a high aspect ratio format can only be achieved by employing a 3D configuration for the current collector. For this, the current collector would need to withstand the rigorous processing techniques used for homogenous deposition of most electrode materials. Moreover, the primary attribute of a current collector is to have an electrochemical inertness across the voltage of device operation and a minimal surface charge resistance facilitating good electron transport from the electrode. Thus towards realizing such configuration, in this report, we demonstrate a one-step CVD process to transform thermally and chemically stable planar stainless steel metallic substrates into micron-sized mesh like 3D architectures with conformal graphene covering on the surface which aids in increasing electrochemical stability and electron transfer.

Such current collectors are clearly advantageous for use with high capacity anode materials, which are plagued by low conductivity. Ceramic materials like MnO$_2$, MoS$_2$, and others have demonstrated excellent capacity (up to 1290 mA h g$^{-1}$ for MoS$_2$) compared to pristine carbon anodes. Several methodologies such as structural tuning and incorporating these materials into carbon host structures has been shown to alleviate the conductivity issue.$^{23-28}$ However, the net volumetric capacity was compromised in such approaches. Of these ceramic anodes, 2D transition metal di-chalcogenides (TMD’s) are particularly interesting compared to oxide counterparts due to better first cycle efficiencies and smaller volume...
changes. In this report, we validate the efficacy of 3D graphene covered stainless-steel current collectors by incorporating 2D MoS2 into the pores using a controlled electrodeposition technique.

Experimental procedure
Fabrication of graphene covered 3D stainless steel
Chemical vapor deposition was done using a split tube furnace fitted with a quartz tube and equipped with a vacuum evacuation feature. The setup has facility for a liquid vapor source connected by a tabulated flask. The flask has a shutoff valve and can be transferred into a glovebox to be filled with inert precursors. Perfluorohexane (aka-C6F14 or tetradecafluorohexane, hereby called PFH) (99% purity and sealed under argon, from Sigma Aldrich) was used as a carbon precursor. 304-grade stainless steel foil (Alfa Acer) was used as the substrate. The substrate-loaded tube was first evacuated and heated to 950 °C while flowing Ar/15% H2 and maintaining the pressure at 10 Torr. Once the desired temperature has reached, H2 flow was stopped and the tube was flushed with pure argon for a moment and then turned off. Vapors of PFH were passed for 10 to 12 minutes, while controlling the inlet flow to maintain the pressure at 600 mTorr. The furnace was then cooled down with the flow of PFH continued until the temperature reached 800 °C, and later with a purge of pure Ar flow. The duration of PFH exposure defines the degree of etch while the rate of cooling dictates the number of graphene layers formed on the surface.

Electro deposition of MoS2
MoS2 was deposited from a solution of 0.5 g L\(^{-1}\) ammonium tetrathiomolybdate ((NH₄)₂MoS₄), 3 g L\(^{-1}\) ammonium chloride (NH₄Cl) and 10.5 g L\(^{-1}\) potassium chloride (KCl) in formamide as reported in previous studies. In the three-electrode setup, the graphene covered stainless steel substrate was used as working electrode, Ag/AgCl as reference electrode and platinum wire as counter electrode. Pulsed electrodeposition was carried out at ~0.6 V (vs. Ag/AgCl) using potentiostat/galvanostat (AUTOLAB PGSTAT 302 N ECOCHEMIE) for 5 minutes with ON/OFF time of 10 s/10 s to ensure uniform deposition on the 3D structure. The electrolyte solution was maintained at 60 °C and under constant stirring during the deposition. The substrate after MoS2 deposition was rinsed using DI water and annealed at 450 °C for 4 hours under Ar atmosphere. Mass loading of MoS2 is measured to be approximately 2 mg cm\(^{-2}\).

Structural characterization
Morphological analysis of graphene covered 3D stainless steel substrates and MoS2 electrodeposited 3D structures was carried out using scanning electron microscope (FEI, Environmental SEM). Cross-sectional morphology was analyzed by cooling the sample in liquid nitrogen and then shear crushing it. Vibrational properties of the graphene and MoS2 were analyzed using Renishaw Raman spectrometer with a 514.5 nm wavelength laser. X-ray photoelectron spectroscopy (XPS) studies were carried out with a spectrophotometer (PHI Quantera SXM) using the monochromatic Al K\(\alpha\) radiation (1486.6 eV).

Electrochemical characterization
Electrochemical measurements were performed by assembling the samples in a CR2032 type coin cell packaging. For the half-cell measurements, an electrochemical test cell was assembled in Ar-filled glove box using the fabricated 3D structures as working electrode, lithium metal foil as the counter/reference electrode and 1 M solution of LiPF\(_6\) in 1:1 (v/v) mixture of ethylene carbonate (EC) and dimethyl carbonate (DMC). Charge discharge cycling tests were conducted using ARBIN Instruments Battery Analyzer while cyclic voltammetry measurements were carried out using a potentiostat/galvanostat (AUTOLAB PGSTAT 302 N ECOCHEMIE).

Results and discussion
Chemical vapor deposition serves as an appropriate tool to synthesize high quality 3D graphene structures essential for high power LIBs. A schematic of the growth process of 3D graphene on stainless steel shown in Fig. 1(a) is a representation of the etching and subsequent nucleation of graphene on the surface. PFH molecules undergo pyrolysis at the high temperature forming highly reactive fluoride ions and carbon atoms. Reaction of metal atoms in stainless steel with the fluoride ions result in metal fluoride which is carried away by the flowing gas assisted by vacuum suction. New energetic surfaces thus

![Fig. 1](image-url) (a) Schematic depiction of the CVD process for etching the surface of stainless steel while simultaneously forming graphene; (b) process conditions employed for the synthesis.
formed favor graphene growth through a process of carbon dissolution and subsequent perspiration as understood from a previous study. The quality of stainless steel, choice of apt precursors and a high degree of process control is necessary for high growth efficiencies. 304-grade austenitic stainless steel foil substrate with limited carbon solubility serves as the best substrate for uniform nucleation of graphene all over the surface. Temperature profile with heating and cooling rates and the dwell time are detrimental for the process and the parameters employed here are shown schematically in Fig. 1(b). Complete purging of the tube with inert (Ar) gas between the reducing H2 gas and the subsequent fluorinated precursor is essential to avoid the formation of any HF species. While the precursor exposure time defines the extent of porosity, an exposure time of 8 to 12 minutes is deemed optimum in this study. The number of graphene layers formed is however not proportionate to the exposure time and is dependent on the cooling rate as reported in our previous study of graphene growth on stainless steel and the justification holds good here.

Morphological characterization of the obtained graphene films on stainless steel surfaces indicate preferential etching of fluoride ions along the grain boundaries resulting in formation of ridges (Fig. 2(a)). Bulk of the grain transforms into a highly porous 3D foam like network (Fig. 2(b)) with a thin layer of graphene coating. Deeper examinations of the pores shown in Fig. 2(c) reveals the high extent of conformity of the graphene layer and pore sizes up to 1 μm. The depth of penetration of the etching process is limited to 10 μm from the surface as observed from the cross-sectional image in Fig. 2(d) implying that the etching is a surface phenomenon. This, however, is comparable to thickness of bulk conventional LIB electrodes fabricated using slurry coating methods with the advantage of a 3D structure facilitating cycling at higher rates. Raman spectrum (Fig. 2(e)) of the carbon layer reflects the profile for 2 to 3 layered graphene with the peaks of G and 2D bands at ~1675 cm⁻¹ and ~2700 cm⁻¹ respectively having a G : D area ratio of 0.3. A low intensity defect induced D peak at ~1275 cm⁻¹ reflects the disorder introduced in the graphene lattice due to the curvature of the pores. Elemental analysis using XPS (ESI, Fig. S1†) revealed no additional elements other than carbon, indicating purity of the graphene lattice. Though PFH has been used to etch the surface of stainless steel, no residual fluoride was observed in the resultant structure. Elemental XPS analysis of the carbon atoms in the sample (ESI, Fig. S1(b)†) revealed a peak which can be deconvoluted into two constituents, a high intensity peak at 284 eV corresponding to sp² carbon and an low intensity peak at 285 eV corresponding to sp³ carbons which are a result of the curvature of graphene on the 3D structure. Absence of a peak above 286 eV confirms the nonexistence of C–F and C–O bonds in the structure.
Graphite is the most widely used anode in LIBs owing to its high capacity and low lithiation potentials. A preliminary measurement in this direction targeted towards testing the 3D graphene structures (ESI, Fig. S2(a)†) reveals extraordinary rate capabilities with a high capacity of 20 μA h cm\(^{-2}\) at a current density 64 μA cm\(^{-2}\) as compared to ~35 μA h cm\(^{-2}\) at a current density of 2 μA h cm\(^{-2}\) for its 2D counterpart. However, large reversible losses in graphite due to the formation of dynamic solid electrolyte interphase (SEI) plague the battery industry. An additional plateau at ~0.7 V in the charge discharge profile (ESI, Fig. S2(b)†) is an indicative of the SEI formation hindering the cyclic stability of the graphene layers.

The evidence of low density of defects from the Raman spectrum indicates the quality of graphene, with its high electronic conductivities turning it into a promising material as a universal current collector for many electrochemically active materials. Recent interest in exploring layered transition metal di-chalcogenide structures as anodes for LIBs motivated electro deposition of MoS\(_2\) onto the graphene layer. Parameters optimized from previously reported protocol\(^{31}\) resulted in uniform homogenous deposit through the entire region of the grain (Fig. 3(a) and (b)) retaining significant pore volume to accommodate volume changes during cycling. The deposition is controlled to form a continuous and conformal coating, as seen from high magnification SEM images (Fig. 3(c)). A rare defect shown in Fig. 3(d) highlights the compact nature and thickness of the MoS\(_2\) layer. With the absence of large pores or pinholes, and the surface is free from deposition of undesired byproducts, which could otherwise clog the pores restricting access to the electrolyte to the interior of the structure. This is a natural consequence of the quality and conformity of the underlying graphene layers, which reduces voltage fluctuations that could lead to the formation of amorphous phases. The distinct and characteristic Raman bands at 390 and 410 cm\(^{-1}\) (Fig. 3(e)) and the absence of additional peaks in the XPS spectra (ESI, Fig. S3†), further confirms the presence of the MoS\(_2\) phase.

Having a layered structure, high theoretical capacity and low lithium intercalation potential (0.8 V) of MoS\(_2\) makes it a promising candidate as anode for LIBs. However, low electronic conductivities of 2D macro particulates in the electrodes impose a barrier towards commercialization. Electrodeposition of nanoparticles of MoS\(_2\) onto 3D current collectors attempts to solve the inherent problems of conductivity by reduction in particle sizes and enhancement in effective electrode/electrolyte interface area for better cyclability at high current rates. Cyclic voltammetry scans (Fig. 4(a)) between 0.1 to 3 V indicate two
peaks at 1.1 V and 0.6 V during the first discharge, corresponding to lithium insertion into MoS₂ and phase change to form 1T-Li₂MoS₂ and the later dissociation of MoS₂ into metallic Mo and Li₂S respectively. Subsequent scans demonstrate recurring cathodic peaks at around 0.8 V and 1.7 V with corresponding anodic peaks at 1.5 V and 2 V respectively, which are characteristic of MoS₂ attributed to reversible conversion of Li₂S and Mo particles to Li₂MoS₂ and the subsequent de-lithiation into MoS₂. Consistent occurrence of peaks at the same position over 3 scans indicate complete reversibility of the lithiation and de-lithiation processes with good MoS₂-graphene interface and thus effective electron conduction through the current collector. Graphene being only few layers thick, has minimal contribution to the active mass while MoS₂ being the current collector. Graphene being only few layers thick, has minimal contribution at voltages <0.5 where graphitic carbon is mostly reactive towards lithium ions. Galvanostatic charge discharge profiles (Fig. 4(b)) present a sloping profile of lithiation and de-lithiation with the high over potential characteristic of conversion anode materials. The additional plateau in the first discharge indicating SEI layer formation and does not affect the performance of the electrode substantially, except for a 0.3 mA h cm⁻² loss in capacity. A high capacity of 1.0 mA h cm⁻² and a retention of ~93% at the end of 50 cycles with a current density of 190 μA cm⁻² support the hypothesis of good cyclic stability of nanoparticles in combination with 3D architecture as compared to 0.15 mA h cm⁻² for electrode-deposited MoS₂ electrode onto 2D graphene current collector (Fig. 4(c)). The 3D MoS₂ electrodes exhibit extreme resilience to higher current rates with the ability to store capacity of 0.5 mA h cm⁻² without any capacity fade over cycling when the current density is increased 8 folds to 1520 μA h cm⁻². A complete regain of the nominal capacity was observed when the cell was cycled again at lower current rates (Fig. 4(d)). This implies excellent structural retention of the electrode and thus the robustness of the electrode-current collector combination to tolerate large current fluctuations.

Conclusions

Using chemical vapor deposition technique, a synthesis process has been developed to etch the surface of stainless steel foils while simultaneously coating it with few-layered graphene. The process has a control on the quality of the deposited graphene, limiting it to 2 to 3 layers with minimal defects and contamination. Having a 3D porous architecture combined with a highly conductive and inert surface coating that does not gravimetrically load the structure, makes the etched stainless-steel-graphene an ideal candidate for current collectors in high capacity/high rate electrochemical devices. The efficacy of the structure to support electrodes under high current rates over prolonged cycling is demonstrated by depositing MoS₂ into the pores. The 3D architecture had resulted in nearly 4-fold improvement in discharge capacity as compared to a 2D architecture. Conformal deposition of MoS₂ achieved by electro deposition technique demonstrated an excellent rate capability and cycle life, showing no signs of electrode degradation. The one-step, simple and scalable synthesis protocol developed here makes it viable for integrating into current energy industry and can prove critical in applications such as thin film batteries and micro devices.

Author contributions

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